



**VA4708** T-79-07-20  
**QUAD HIGH-SPEED,  
 FAST-SETTLING,  
 HIGH OUTPUT CURRENT  
 OPERATIONAL AMPLIFIER,  $A_{CL} \geq 3$**

**FEATURES**

- Fast Settling Time:  $\pm 0.1\%$  in 150ns
- High Slew Rate: 90V/ $\mu$ s
- Large Gain Bandwidth: 100MHz
- Full Power Bandwidth: 4.8MHz at 6V p-p
- Ease of Use: Internally Compensated for  $A_{CL} \geq 3$  with 50° - 60° phase margin
- Large Output Current:  $\pm 50$ mA
- Low Supply Voltage Operation:  $\pm 4$ V
- Minimal Crosstalk: >90 dB Separation
- Short Circuit Protection
- Available in Commercial Version

**DESCRIPTION**

The VA4708 offers the high-speed and fast-settling advantages of the VA708 in a quad package configuration. The high slew rate, output drive and open-loop gain allows the amplifier to fit analog amplification and high speed processing applications, capable of driving large capacitance loads at high speeds.

**ABSOLUTE MAXIMUM RATINGS**

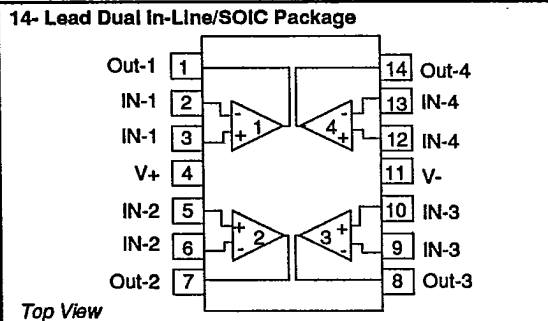
Supply Voltages	$\pm 6$ V
Differential Input Voltage	$\pm 9$ V
Common Mode Input Voltage	$ V_{S}  - 0.5$ V
Power Dissipation ( $T_A = 70^\circ\text{C}$ , Note 1)	550mW
Output Short Circuit Current Duration (Note 2)	Indefinite
Operating Temperature Range:	
Commercial (4708 J)	0° to 70°C
Storage Temperature Range	-65° to +150°C
Lead Temperature (Soldering to 60 Sec.)	300°C

Note 1: Power derating above  $T_A = 70^\circ\text{C}$  to be based on a maximum junction temperature of 150°C and the thermal resistance factors of  $\theta_{JC} = 75^\circ\text{C/W}$  and  $\theta_{JA} = 145^\circ\text{C/W}$ .  
 Note 2: Continuous short-circuit protection is allowed on one amplifier per time up to case temperatures of 85°C and ambient temperatures of 30°C.

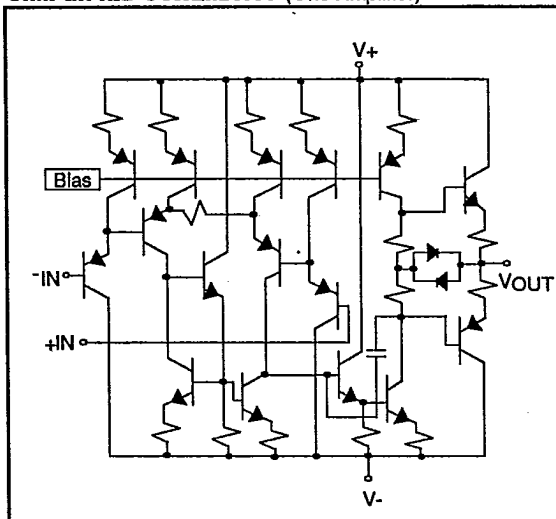
**PACKAGE TYPES AVAILABLE**

- 14-Pin Plastic DIP
- 14-Pin SOIC

**CONNECTION DIAGRAM**



**SIMPLIFIED SCHEMATIC (One Amplifier)**



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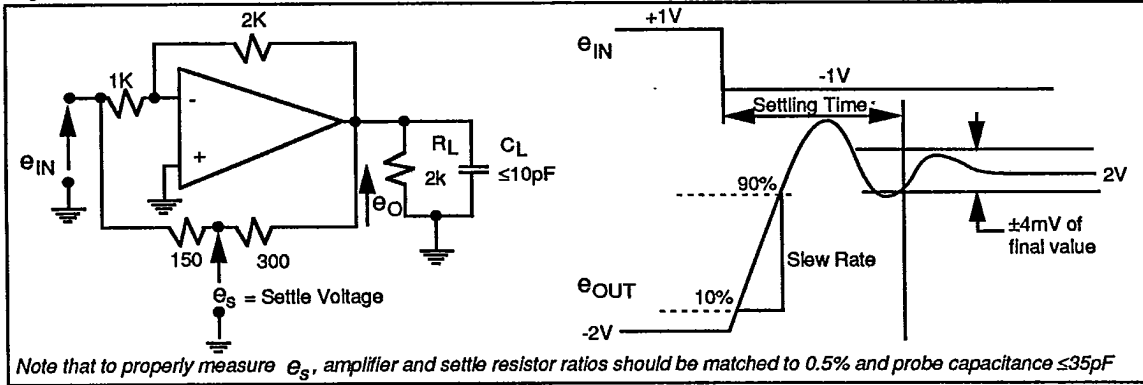
**ELECTRICAL CHARACTERISTICS** ( $V_S = \pm 5V$ ,  $T_A = 25^\circ C$  unless otherwise stated) (each amplifier)

PARAMETER	SYMBOL	CONDITIONS	VA4708J			UNITS
			MIN	TYP	MAX	
Input Offset Voltage $T_{Min}$ to $T_{Max}$	$V_{OS}$	$0^\circ \leq T_A \leq 70^\circ C$		5	12	mV
		$-55 \leq T_A \leq 125^\circ C$		8	16	
Average Offset Voltage Drift	$\frac{\Delta V_{OS}}{\Delta T}$	$0^\circ \leq T_A \leq 70^\circ C$ $-55 \leq T_A \leq 125^\circ C$		20		$\mu V/^\circ C$
Input Bias Current $T_{Min}$ to $T_{Max}$	$I_B$	$0^\circ \leq T_A \leq 70^\circ C$		650	1100	nA
		$-55 \leq T_A \leq 125^\circ C$			1700	
Input Offset Current	$I_{OS}$			35	120	nA
Input Common Mode Range	$V_{CM}$		+3 -4	+3.5 -4.5		V
Differential Input Resistance	$R_{IND}$	(Note 1)	3	10		$M\Omega$
Common Mode Input Resistance	$R_{INC}$	(Note 1)	4	8		$M\Omega$
Differential Input Capacitance	$C_{IND}$	(Note 1)		2		pF
Common Mode Input Capacitance	$C_{INC}$	(Note 1)		3		pF
Input Voltage Noise	$e_N$	BW = 10Hz to 100KHz		12		$\mu V_{RMS}$
Open Loop Voltage Gain	$A_V$	$V_{OUT} = \pm 3V$ $R_L = 2k\Omega$	2	5		V/mV
Output Voltage Swing	$V_{OUT}$	$R_L = 2k\Omega$	$\pm 3.5$			V
		$R_L = 51\Omega$	$\pm 2.0$	$\pm 2.4$		
Power Supply Current (All Four Amplifiers)	$I_S$			30	40	mA
Common Mode Rejection Ratio	CMRR	$V_{CM} = \pm 2V$	60	70		dB
Power Supply Rejection Ratio	PSRR	$\Delta V_{PS} = \pm 0.5V$	60	66		dB
Slew Rate	SR	10-90% of Leading Edge (Figure 1)	60	90		V/ $\mu s$
Settling Time	$t_S$	To $\pm 0.1\%$ ( $\pm 4mV$ ) of Final Value (Figure 1, Note 1)		150	200	ns
Gain Bandwidth Product	GBW			100		MHz
Small Signal Rise/Fall Time	$t_r / t_f$	$E_O = \pm 100mV$ 10-90% (Figure 1)		7		ns
Full Power Bandwidth	$BW_{FP}$	$R_L = 2k\Omega$ $C_L = 50pF$ $V_{OUT} = 6V_{p-p}$		4.8		MHz
Amplifier to Amplifier Crosstalk		Input Referenced $f = 10KHz$ (Figure 2)		-96		dB

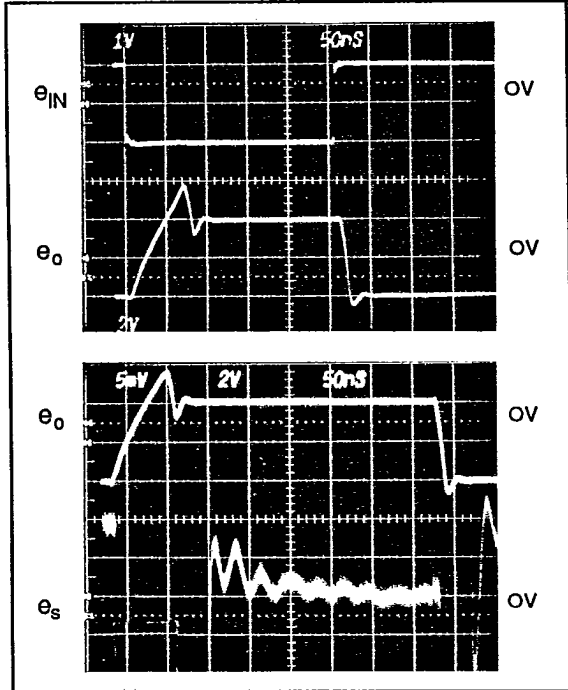
Notes: 1. Not tested, guaranteed by design.

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Figure 1: Settling Time and Slew Rate Test Circuit



Large Signal Response



Small Signal Response

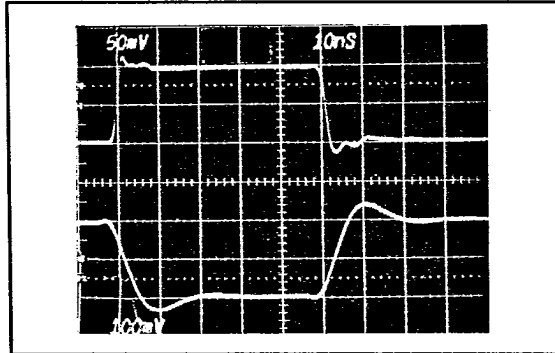
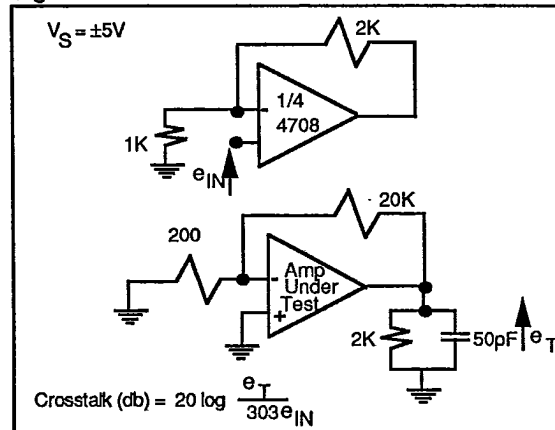


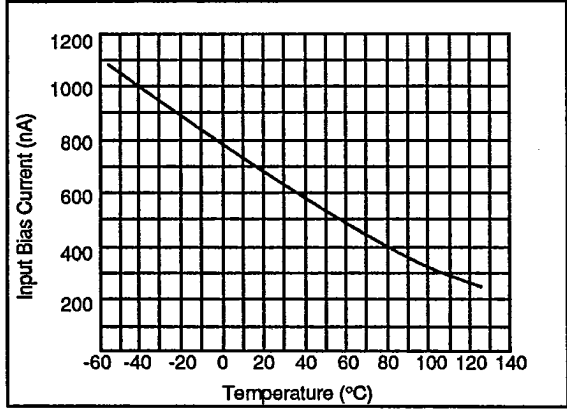
Figure 2: Crosstalk Test Circuit



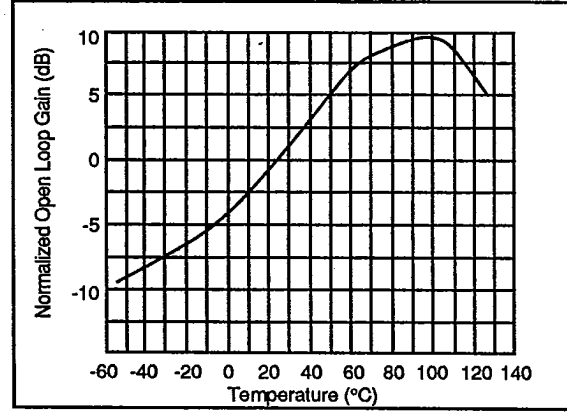
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**TYPICAL PERFORMANCE CHARACTERISTICS** ( $V_S = \pm 5V$ ,  $T_A = 25^\circ C$  unless otherwise stated)

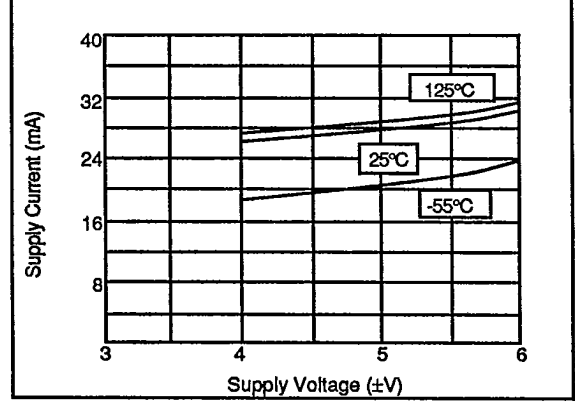
**Input Bias Current vs Temperature**



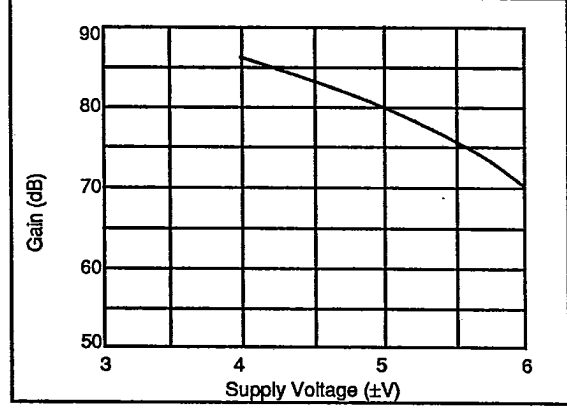
**Normalized Open Loop Gain vs Temperature**



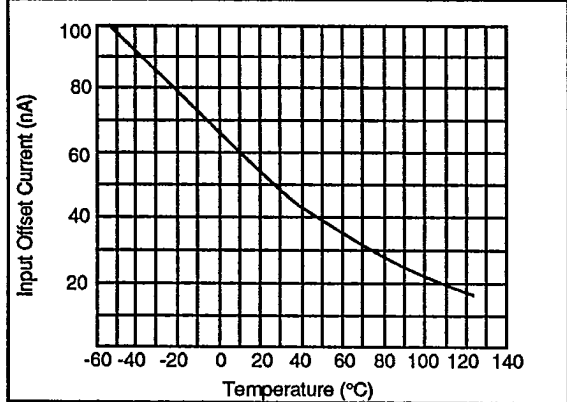
**Supply Current vs Supply Voltage**



**Open Loop Gain vs Supply Voltage**



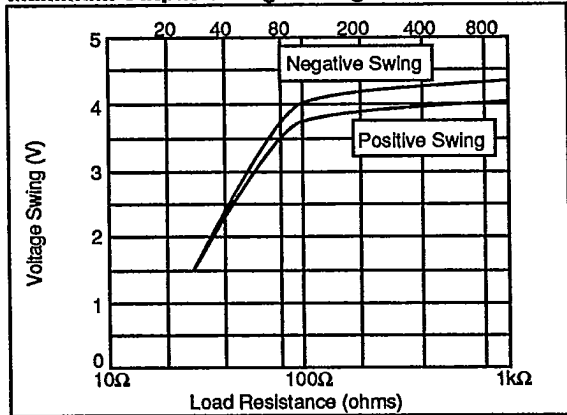
**Input Offset Current vs Temperature**



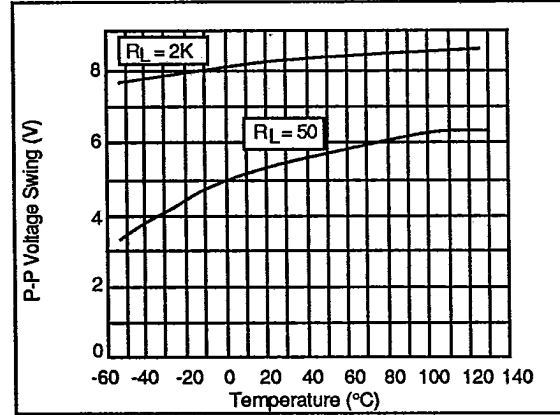
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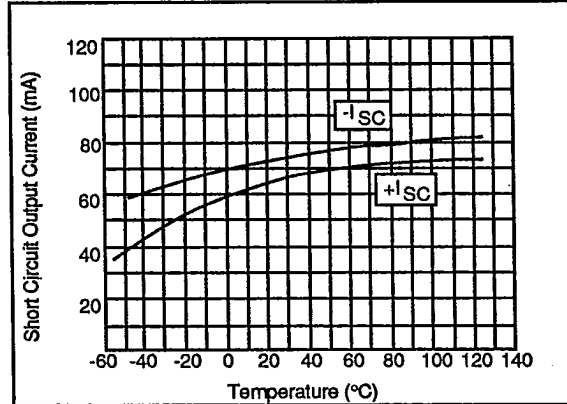
**Maximum Output Voltage Swing vs Load Resistance**



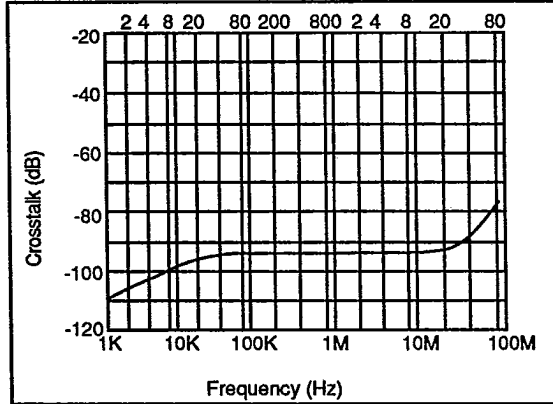
**Maximum Output Voltage Swing vs Temperature**



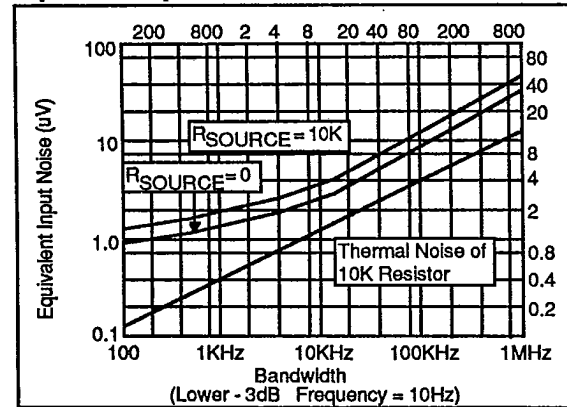
**Short Circuit Output Current vs Temperature**



**Amplifier/Amplifier Crosstalk vs Frequency**



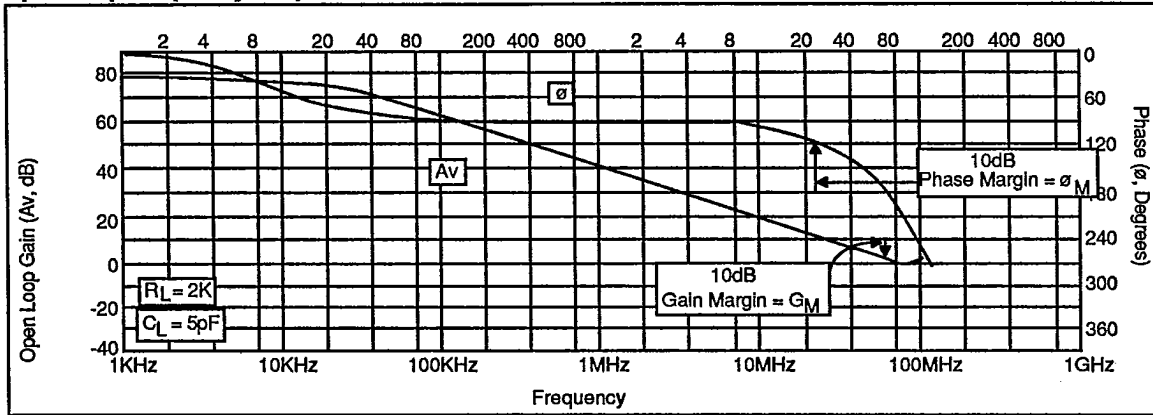
**Equivalent Input Noise vs Bandwidth**



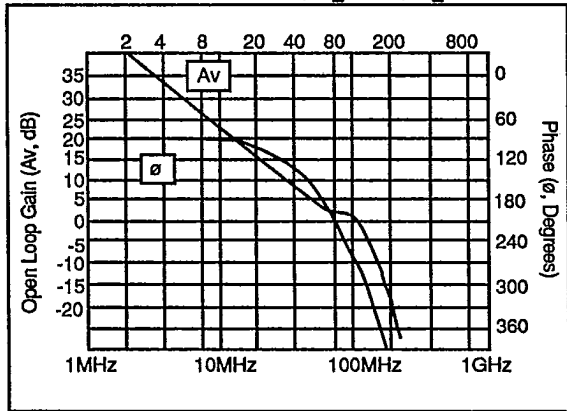
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**TYPICAL PERFORMANCE CHARACTERISTICS** ( $V_S = \pm 5V$ ,  $T_A = 25^\circ C$  unless otherwise stated)

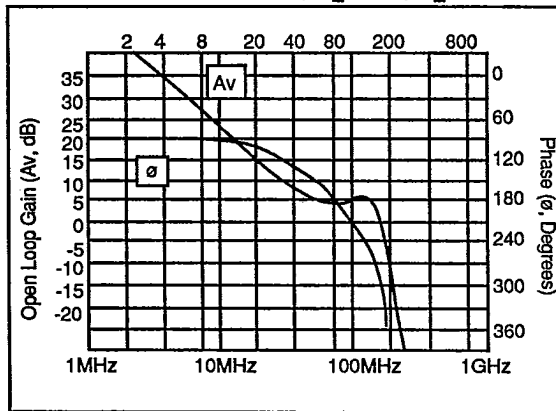
**Open Loop Frequency Response**



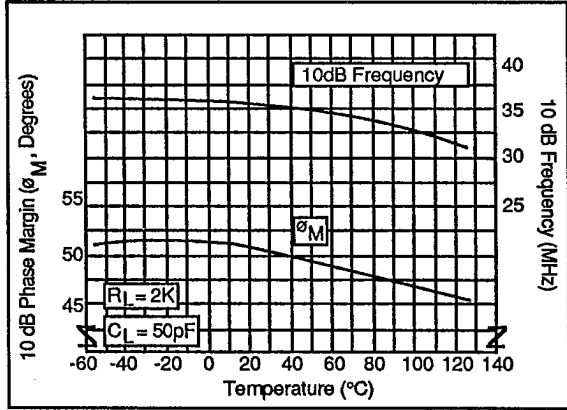
**Open Loop Freq. Response,  $R_L = 50\Omega$ ,  $C_L = 50pF$**



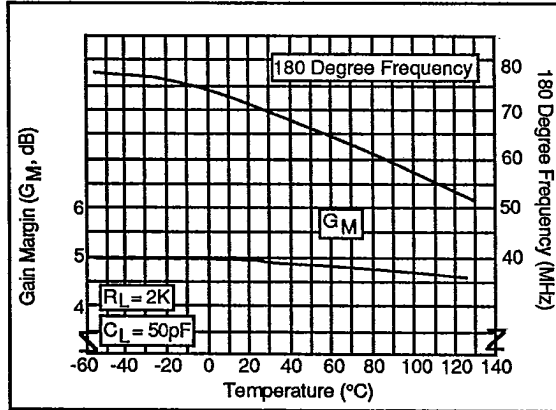
**Open Loop Freq. Response,  $R_L = 2K\Omega$ ,  $C_L = 50pF$**



**10dB Phase Margin and 10dB Freq. vs Temp.**



**Gain Margin and 180 Degree Freq. vs Temp.**



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**APPLICATION INFORMATION****AC Characteristics**

The 35MHz 10dB crossover point of the VA4708 is achieved without feed forward compensation, a technique which can produce long tails in the recovery characteristics. The single pole rolloff follows the classic 20dB/decade slope to frequencies approaching 50MHz. The 10dB (3.2 V/V) phase margin of 50°, even with a capacitive load of 50pF, gives stable and predictable performance down to non-inverting gain configurations of approximately 3 V/V (inverting gains of -2V/V). At frequencies beyond 50MHz, the 20dB/decade slope is disturbed by an output stage zero, the damping factor of which is dependent upon the  $R_L$ ,  $C_L$  load combination. This results in loss of gain margin (gain at loop phase = 360°) at frequencies of 70 to 100MHz which at a gain margin of 5dB ( $R_L = 2K$ ,  $C_L = 50pF$ ) results in a peak in the gain of 3 amplifier configurations as shown in Figures 3 and 4.

Figure 3 shows a blow up of the open loop characteristics in the 10MHz to 200MHz frequency range, as well as the corresponding closed loop characteristics for a gain of 3 non-inverting amplifier at similar load conditions. It should be noted that the open loop characteristic does not show the additional phase shift caused by the input capacitance pole — this is why the closed loop peaking at 30 to 40MHz is greater than what would be expected from the 50 to 60 degrees of phase margin indicated by the open loop characteristics. Corresponding small signal step response characteristics show well-behaved pulse waveforms with 16-33% overshoot.

The input capacitive pole can be neutralized by adding a feedback capacitor to  $R_2$ . The value of capacitance is selected according to  $R_1 C_{IN} = R_2 C_{FB}$ , where  $C_{IN}$  is the sum of the common mode and differential input capacitance  $\approx 5pF$ . For  $R_2 = 2R_1$ ,  $C_{FB} = C_{IN}/2 \approx 2.5pF$ .

Figure 4 shows the results of this feedback capacitor addition. Neutralizing the input capacitance demonstrates the peaking that can result from the loss of gain margin at 70 to 100MHz. As the load time constant ( $R_L C_L$ ) increases the peaking gets progressively worse  $\approx 6dB$  at  $R_L = 2K$ ,  $C_L = 50pF$ . The step response waveforms are as expected with a very strong 88MHz ring being exhibited at  $R_L = 2K$ ,  $C_L = 50pF$  and no overshoot at  $R_L = 50\Omega$ ,  $C_L = 5pF$ .

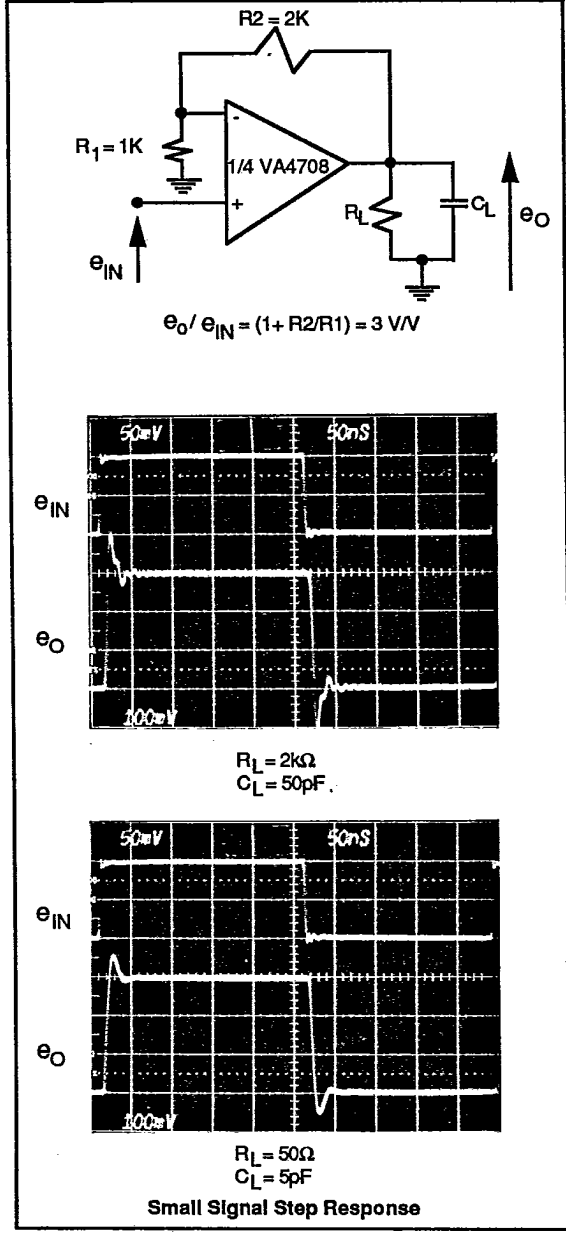
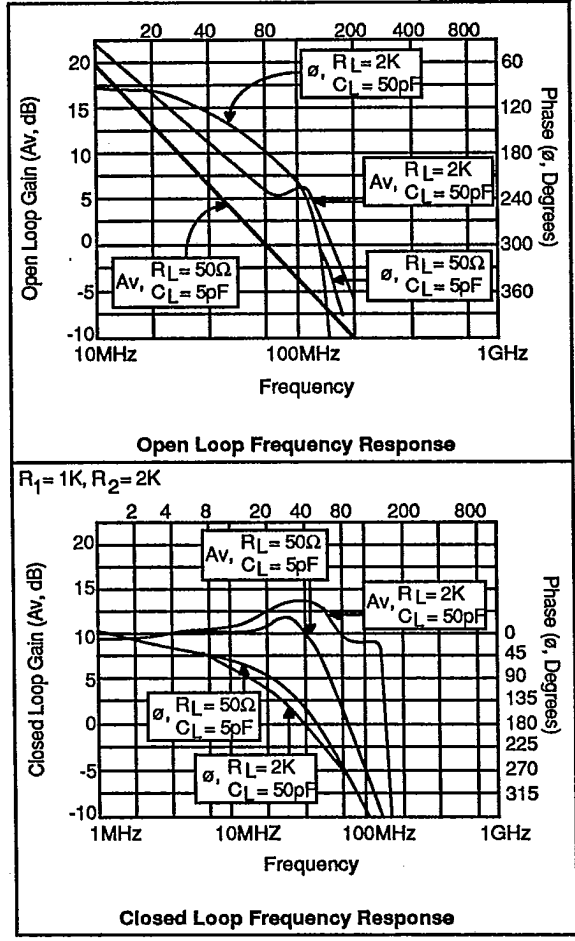
**Layout Considerations**

As with any high-speed wideband amplifier, certain layout considerations are necessary to ensure stable operation. All connections to the amplifier should be kept as short as possible, and the power supplies bypassed with 0.1 $\mu$ F capacitors to signal ground. It is suggested that a ground plane be considered as the best method for ensuring stability because it minimizes stray inductance and unwanted coupling in the ground signal paths.

To minimize capacitive effects, resistor values should be kept as small as possible, consistent with the application.

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**Figure 3: Frequency and Time Domain Response Characteristics, Av=3**





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Figure 4: Response Characteristics with Input Pole Cancellation,  $A_v=3$

